Design and characterization of extreme-ultraviolet broadband mirrors for attosecond science

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A novel multilayer mirror was designed and fabricated based on a recently developed three-material technology aimed both at reaching reflectivities of about 20% and at controlling dispersion over a bandwidth covering photon energies between 35 and 50 eV. The spectral phase upon reflection was retrieved by measuring interferences in a two-color ionization process using high-order harmonics produced from a titanium:sapphire laser. We demonstrate the feasibility of designing and characterizing phase-controlled broadband optics in the extreme-ultraviolet domain, which should facilitate the manipulation of attosecond pulses for applications.© 2006 Optical Society of America

The technology of x-ray and extreme ultraviolet (XUV) ultrashort light sources has made tremendous progress during the past few years, thus opening up a whole range of possibilities for investigating problems in material and life sciences. This leap forward in XUV light sources requires stringent concomitant progress in dedicated optical instrumentation, starting from the simplest and most ubiquitous elements: mirrors. The simple transport of attosecond XUV pulses is difficult, since the spectral phase has to be maintained over spectral bandwidths spanning tens of electron volts. Moreover, it has been shown that attosecond pulses obtained from laser-driven high-harmonic generation sources often present an intrinsic chirp that has to be compensated for in order to obtain ultrashort light pulses. Aperiodic multilayer mirror technology has been suggested to control dispersion in the XUV domain. Reflection off a mirror surface can be described as the product of the spectral amplitude $E(\omega)$ of a light pulse and the reflection coefficient, $r(\omega)$, of the mirror, which includes an amplitude and a phase (Fig. 1). The design of broadband mirrors implies characterizing both the reflectance $R(\omega)$ and the phase $\varphi(\omega)$ or, equivalently, the phase variation $\Delta \varphi/\Delta \omega$ over the mirror spectral range. In this Letter we report the characterization of both the reflectance and the phase of a broadband XUV mirror with high reflectivity and phase control for photon energies around 40 eV.

The multilayer mirror used in this study represents a step toward aperiodic multilayer mirrors, albeit with a simpler design. The mirror was developed for the spectral region around 40 eV, for which the conversion efficiency for high-order harmonic generation in argon reaches high values, and which is therefore particularly well suited to applications in attosecond metrology. While standard mirrors around 40 eV consist of periodic stacks of only two materials, such as Mo/Si or B$_4$C/Si, here we added a third material to the mirror, which now consists of Mo/Si/B$_4$C. As shown in Fig. 1, we superimposed several periods (2 and 4) of two different multilayers, with thicknesses 16.3 and 40.6 nm, leading to reflectivity maxima at 40 eV for the thinnest and 33 and 50 eV for the thickest. This allows us to achieve almost 20% reflectivity over a 20 eV bandwidth centered around 42 eV. The mirror tested here was specifically designed for optimizing the reflectivity over a large bandwidth while keeping a constant phase variation. The choice of design was guided by numerical simulations using refractive index data.

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The pump beam is focused into a 3 mm static argon gas cell (30 hPa) with a 50 cm spherical mirror to generate odd high harmonics. The generated harmonics are first separated from the laser light by a 200 nm thick aluminum filter, then pass through a 1.5 mm hole in the middle of a spherical mirror designed to match the divergence of the XUV and probe IR beams. Both are then focused, either at normal incidence by the 20 cm focal length spherical multilayer mirror or at grazing incidence by a platinum-coated mirror (not shown), into the sensitive region of a magnetic bottle electron time-of-flight spectrometer, filled with a rare gas at a few $10^{-4}$ of hectopascals of static pressure. Photoionization of the rare gas by the XUV radiation leads to time-of-flight electron spectra that depend on the pump–probe delay. Absorption of the odd-order high-harmonic photons yields discrete peaks in the spectra, separated by twice the laser photon energy; the probe field induces additional absorption or emission of IR photons, appearing as sidebands. Each sideband has contributions from two neighboring harmonics and contains information about their relative phases. The sideband intensity is proportional to $\cos(\Delta \phi_{q+1} + 2\omega_0 \tau)$, where $\Delta \phi_{q+1} = \phi_{q+2} - \phi_q$, $q$ and $q + 2$ being two consecutive (odd) harmonic orders, $\omega_0$ the laser frequency, and $\tau$ the delay between the XUV and IR fields. The measured $\Delta \phi_{q+1}$ is the sum of four contributions:

$$\Delta \phi_{q+1} = \Delta \phi_{q+1}^{\text{harm}} + \Delta \phi_{q+1}^{\text{atom}} + \Delta \phi_{q+1}^{\text{Al}} + \Delta \phi_{q+1}^{\text{mirror}},$$

(1)

$$\Delta \phi_{q+1}^{\text{harm}} = \Delta \phi_{q+1}^{\text{Al}} + \Delta \phi_{q+1}^{\text{mirror}},$$

(2)

$$\Delta \phi_{q+1}^{\text{atom}} = \Delta \phi_{q+1}^{\text{Al}} + \Delta \phi_{q+1}^{\text{mirror}},$$

(3)

$$\Delta \phi_{q+1}^{\text{mirror}} = \Delta \phi_{q+1}^{\text{Al}} + \Delta \phi_{q+1}^{\text{mirror}},$$

(4)

The pump–probe setup used for characterizing the phase variation induced by broadband XUV multilayer mirrors. The measurement is based on reconstructing attosecond pulse trains synthesized in a laser-driven high-harmonic source and reflected off the mirror. The multilayer structure was deposited on a spherical mirror substrate with a 20 cm focal length.
intrinsic positive attosecond chirp of the harmonics, with a slight contribution from the negatively dispersive aluminum filter. The electron signals for harmonics 29 and 31 were very low and could not be used to measure the sideband phase oscillations. For these last two points the harmonic phases were extrapolated by solving the saddle point equations within the strong-field approximation. The results with the multilayer mirror exhibit rapid phase variations, especially around 30 eV. By subtracting the results obtained with both mirrors, we deduced the effect of the multilayer mirror on the phase variation, \( \partial \phi / \partial \omega = \Delta \phi^{\text{mirror}} / 2 \omega_0 \), as indicated by the solid curve in Fig. 2(b). Remarkably, the discrepancies between experimental results and simulations are quite close to those shown for the reflectance in Fig. 2(a). The rapid variation around 30 eV corresponds to the passage from total surface reflection to interference reflection for higher photon energies. The full mirror range could not be explored because of the low high-harmonic spectral cutoff energy in argon.

Within the spectral range of the mirror that we could sample, the negative dispersion induced by the multilayer mirror reduces the intrinsic chirp of the harmonic radiation, in principle making it possible to temporally compress the reflected attosecond pulses. Unfortunately, the relatively high reflectivity for the low-order harmonics, combined with the phase jump around 30 eV, prevent significant compression of the attosecond pulses below 250 as. The high reflectivity in the lower photon energy region (below 30 eV) could be significantly reduced by using filters combining aluminum and silicon materials. Neon could also be used to generate harmonics over a broad spectral range spanning the whole optimized region of the multilayer, thus achieving pulse compression below 150 as with optimized phase compensation.

In summary, we have designed and characterized a new multilayer mirror with broad reflectance around 40 eV featuring custom dispersion control to compress attosecond XUV pulses. To the best of our knowledge, this is the first time a broadband phase measurement has been performed in the notoriously difficult XUV wavelength region. These findings reveal that, despite the current uncertainties in material properties such as refractive index, deposited density, and surface roughness, dispersion control of ultrashort light pulses can be extended from the visible-infrared to the XUV–soft-x-ray spectral range. Such instrumentation is crucial for shaping and transporting attosecond pulses over a large and tunable energy range.

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References